NSN 5962-01-293-7710

Memory Microcircuit - Page 1 of 1

View Online at https://aerobasegroup.com/nsn/5962-01-293-7710

Body Length:

Between 0.755 inches and 0.785 inches

Body Width:

0.302 inches

Body Height:

Between 0.145 inches and 0.175 inches

Maximum Power Dissipation Rating:

332.8 milliwatts

Operating Tempurature Range:

+0.0/+70.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Bipolar and programmable and schottky and w/enable

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

6 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Time Rating Per Chacteristic:

50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

